

搭载SiC MOSFET驱动专用栅极驱动电路

Integrates Gate Drive Circuit Dedicated for SiC MOSFET



SiC MOSFET驱动用准谐振AC/DC转换器控制IC

Quasi-Resonant AC/DC Converter Control IC for SiC MOSFET Drive



BD7682FJ-LB, BD7683FJ-LB, BD7684FJ-LB, BD7685FJ-LB

特点

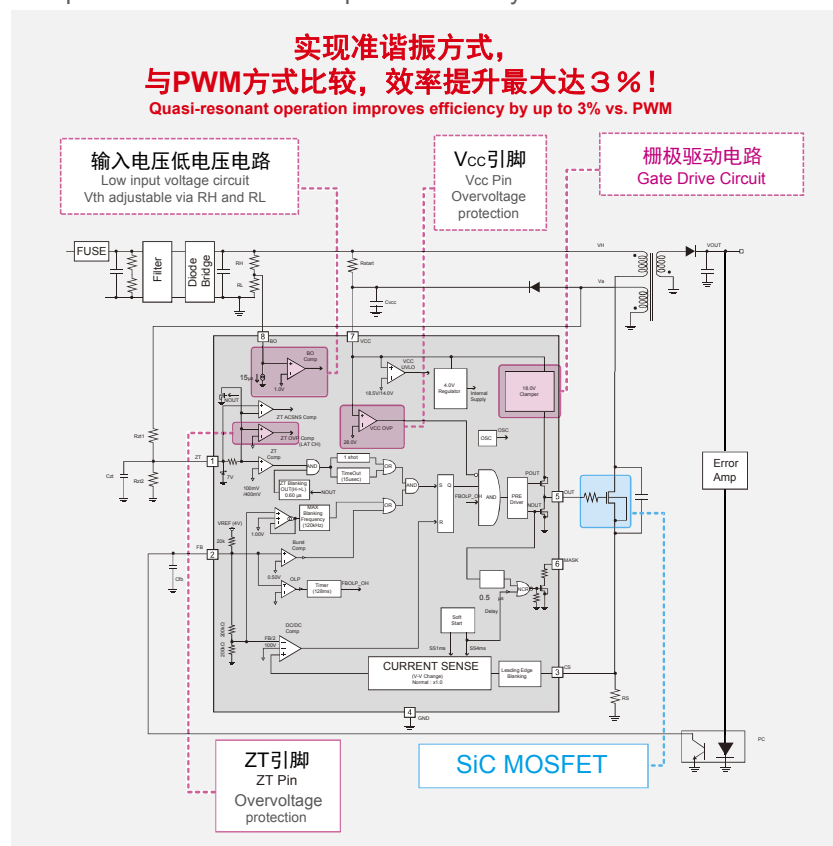
- 充分发挥SiC MOSFET的性能的驱动器电路
Optimized drive circuit maximizes SiC MOSFET performance
- 采用低噪声、高效率的准谐振方式
最大支持150W电源
Low noise, high efficiency quasi-resonant operation supports up to 150W
- 搭载众多保护功能，AC 690V高电压下也可工作
Multiple protection functions enable high voltage operation (AC Max. 690V)

应用

- 工业设备（逆变器、FA、伺服等）
Industrial equipment (i.e. inverters, FA, servos)
- 智能仪表
Smart meters

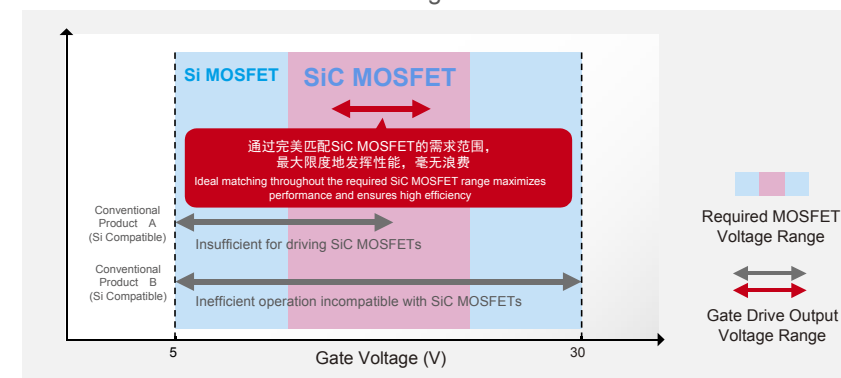
搭载丰富的保护电路，有助于可靠性提升

Multiple Protection Circuits Improve Reliability



MOSFET与栅极驱动电路的匹配

MOSFET-Gate Drive Circuit Matching



AC/DC转换器驱动时的Si MOSFET与SiC MOSFET效率比较

Efficiency Comparison : Si MOSFET vs. SiC MOSFET (During AC/DC Converter Operation)

